imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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Application Specific Discretes A.S.D.™

FEATURES

- HIGH VOLTAGE BREAKOVER DIODE: V_{BO MIN} = 195 or 215 V
- $\scriptstyle \bullet$ HIGH HOLDING CURRENT STRUCTURE : I_{H} > 50 mA
- HIGH PEAK CURRENT PULSE CAPABILITY : $I_{TRM} = 50 \text{ A}$
- DIRECT OPERATION ON 220/240 VAC MAINS CIRCUITS

BENEFITS

- SPACE SAVING THANKS TO MONOLOTHIC FUNCTION INTEGRATION
- HIGH RELIABILITY WITH PLANAR TECHNOLOGY

DESCRIPTION

The LIC01 has been especially designed for high voltage pulse generation circuits such as light ignitors for :

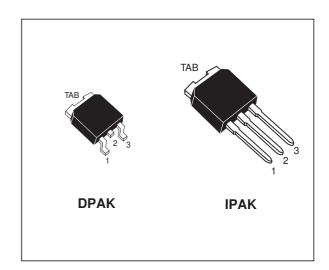
- . High pressure sodium lamp
- . Lamp flashing circuit
- . Metal Halid lamp

It uses a high performance planar diffused technology device suitable for high surge current operation in rugged environmental conditions.

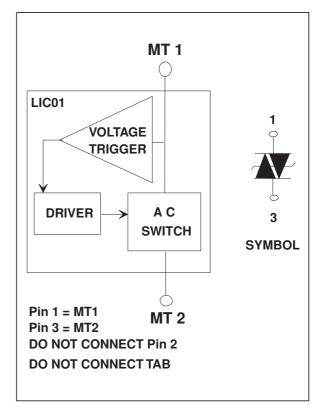
When the voltage across the device reaches the breakover voltage, it decreases from an off-state to low voltage on-state condition. When the current through the circuit drops below the holding current $I_{\rm H}$, the device comes back to the off-state.

DEVICE TYPE	BREAKDOWN VOLTAGE RANGE
LIC01-195	V _{BO} min: 195V V _{BO} max: 230V
LIC01-215	V _{BO} min: 215V V _{BO} max: 255V

LIGHT IGNITION CIRCUIT



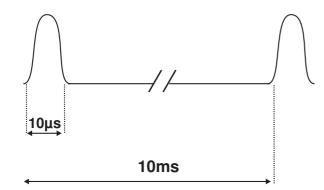
FUNCTIONAL DIAGRAM



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
I _{TRM}	Repetitive surge peak on state current	±50	A
I _{T(RMS)}	RMS on state current	1.2	А
di/dt	Critical rate of rise on state current	80	A/μs
V _{DRM} / V _{RRM}	Repetitive peak off state voltage	180	V
Tstg	Storage junction temperature range	- 40 to + 125	°C
Tj	Operating junction temperature range	-20 to 125	°C
TL	Maximum lead temperature for soldering during	260	°C

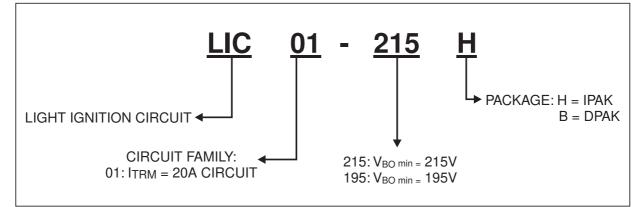
Note 1 : Test current waveform



THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth(j-a)	Junction to ambient	100	°C/W
Rth(j-c)	Junction to case	3.5	°C/W

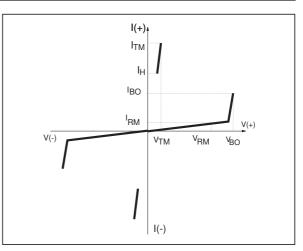
ORDERING INFORMATION



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ELECTRICAL CHARACTERISTICS

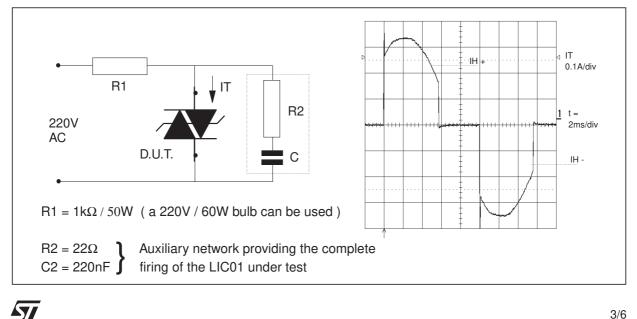
Symbol	Parameters	
V _{RM}	Stand-off voltage	
V _{TM}	On-state voltage	
V _{BO}	Breakover voltage	
I _{TM}	On-state current	
Iн	Holding current	
I _{BO} Breakover current		
I _{RM}	I _{RM} Leakage current	

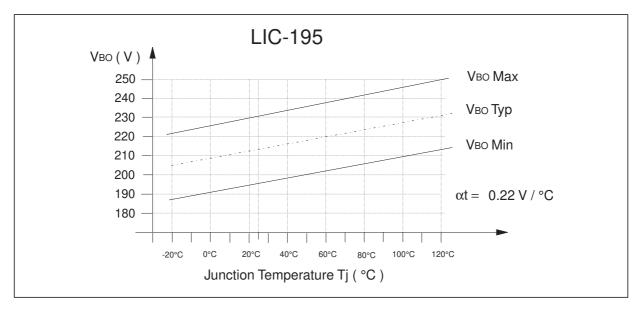


ELECTRICAL PARAMETERS

Symbol	Test	Value	Unit			
I _{RM}	V _D = V _{RM} 180V		Tj = 25°C	MAX	5	μA
			Tj = 125°C	MAX	50	μA
V _{BO}	I _{BO}	LIC01-195	Tj = 25°C	MIN	195	V
				MAX	230	
		LIC01-215	Tj = 25°C	MIN	215	V
				MAX	255	
I _{BO}	V _{BO} max.		Tj = 25°C	TYP	200	μA
				MAX	500	
I _H	I _T = 350mA		Tj = 25°C	MIN	50	mA
V _{TM}	I _{TM} = 1A		Tj = 25°C	MAX	5	V

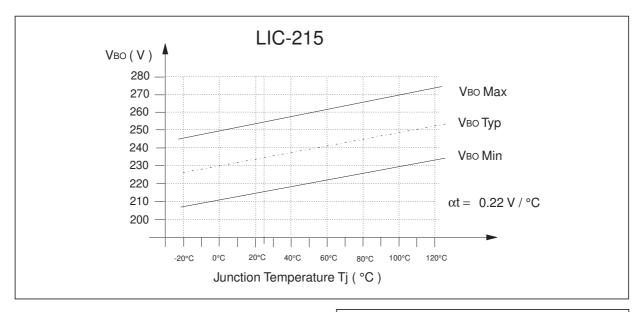
HOLDING CURRENT TEST CIRCUIT





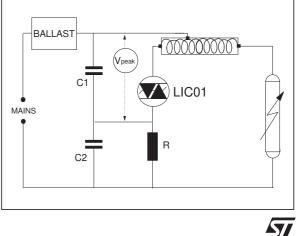
VARIATION OF V_{BO} VERSUS JUNCTION TEMPERATURE



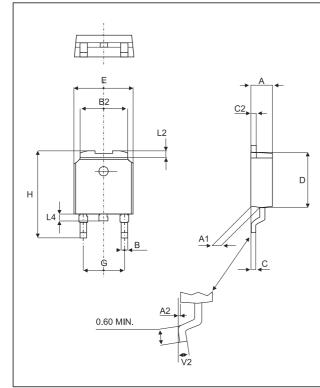


TYPICAL APPLICATION

When the peak voltage across C1 reaches the break over voltage VBO of the LIC01, this device turns on and produces a pulse of current through the primary of the transformer. In turn, the transformer generates high voltage pulses across the lamp.

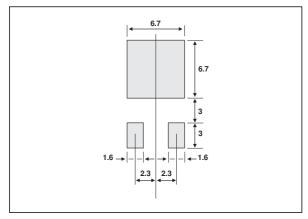


PACKAGE MECHANICAL DATA DPAK (Plastic)



	DIMENSIONS						
REF.	Millimeters			Inches			
	Min.	Тур.	Max	Min.	Тур.	Max.	
А	2.20		2.40	0.086		0.094	
A1	0.90		1.10	0.035		0.043	
A2	0.03		0.23	0.001		0.009	
В	0.64		0.90	0.025		0.035	
B2	5.20		5.40	0.204		0.212	
С	0.45		0.60	0.017		0.023	
C2	0.48		0.60	0.018		0.023	
D	6.00		6.20	0.236		0.244	
Е	6.40		6.60	0.251		0.259	
G	4.40		4.60	0.173		0.181	
Н	9.35		10.10	0.368		0.397	
L2		0.80			0.031		
L4	0.60		1.00	0.023		0.039	
V2	0°		8°	0°		8°	

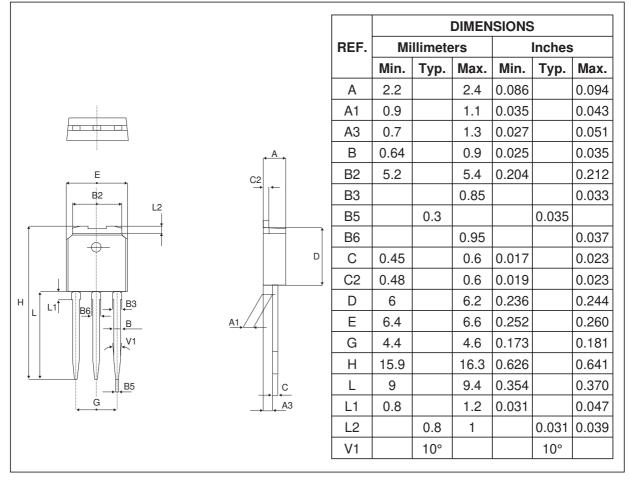
FOOT PRINT DIMENSIONS (in millimeters)



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PACKAGE MECHANICAL DATA

IPAK (Plastic)



OTHER INFORMATION

Туре	Marking	Package	Weight	Base qty	Delivery mode
LIC01-xxxH	LIC01-xxxH	IPAK	0.4 g	75	Tube
LIC01-xxxB	LIC01-xxxB	DPAK	0.3 g	75	Tube

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